BT258S-800LT

SCR logic level, high temperature

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{GT}	gate trigger current	V_D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 8</u>	20	-	50	μA
Dynamic chara	acteristics					
dV _D /dt	rate of rise of off-state voltage	$\label{eq:VDM} \begin{array}{l} V_{DM} = 536 \; V; \; T_{j} = 150 \; ^{\circ}\text{C}; \; R_{GK} = 100 \; \Omega; \\ (V_{DM} = 67\% \; of \; V_{DRM}); \; exponential \\ waveform; \; \underline{Fig. \; 13} \end{array}$	35	70	-	V/µs

[1] Operation above junction temperatures of 110 °C may require the use of a gate to cathode resistor of 1 k Ω or less.

5. Pinning information

Table 2. F	Pinning inf	formation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	[]	А -Ң К
2	А	anode		G sym037
3	G	gate		Syntosi
mb	A	mounting base; connected to anode	DPAK (SOT428)	

6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
BT258S-800LT	DPAK	plastic single-ended surface-mounted package (DPAK); 3 leads (one lead cropped)	SOT428			

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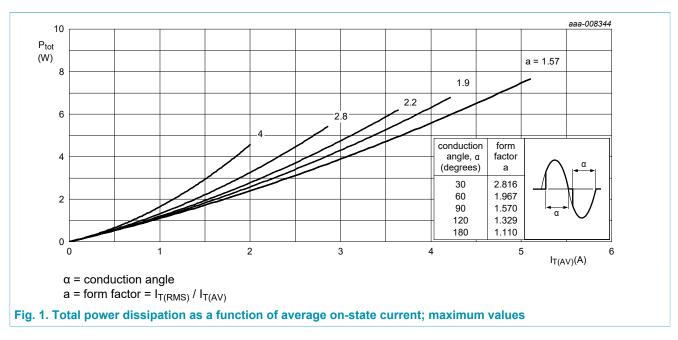
7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage			-	800	V
V _{RRM}	repetitive peak reverse voltage			-	800	V
I _{T(AV)}	average on-state current	half sine wave; T _{mb} ≤ 135 °C; <u>Fig. 1</u>		-	5	А
I _{T(RMS)}	RMS on-state current	half sine wave; T _{mb} ≤ 135 °C; <u>Fig. 2;</u> <u>Fig. 3</u>		-	8	A
I _{TSM}	non-repetitive peak on- state current	half sine wave; T _{j(init)} = 25 °C; t _p = 10 ms; Fig. 4; Fig. 5		-	75	A
		half sine wave; $T_{j(init)}$ = 25 °C; t_p = 8.3 ms		-	82	А
l ² t	I ² t for fusing	t _p = 10 ms; sine-wave pulse		-	28	A²s
dl _T /dt	rate of rise of on-state current	I _G = 50 mA		-	50	A/µs
I _{GM}	peak gate current			-	2	А
P _{GM}	peak gate power			-	5	W
P _{G(AV)}	average gate power	over any 20 ms period		-	0.5	W
T _{stg}	storage temperature			-40	150	°C
Tj	junction temperature		[1]	-	150	°C

[1] Operation above junction temperatures of 110 $^{\circ}$ C may require the use of a gate to cathode resistor of 1 k Ω or less.

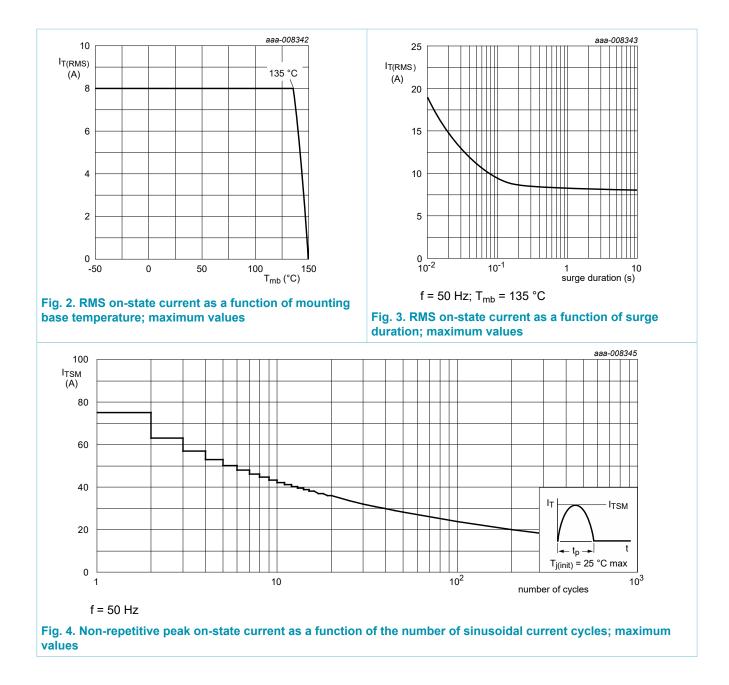


Product data sheet

3/12

BT258S-800LT

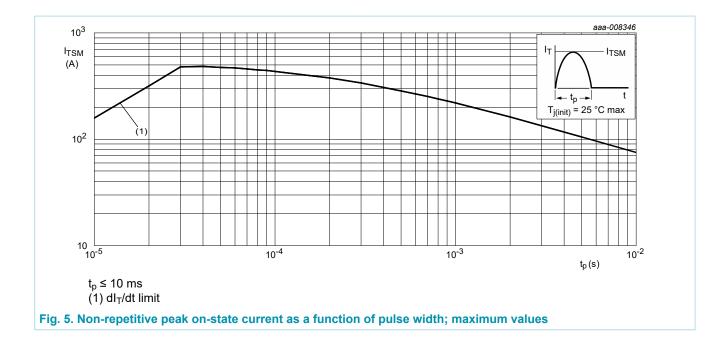
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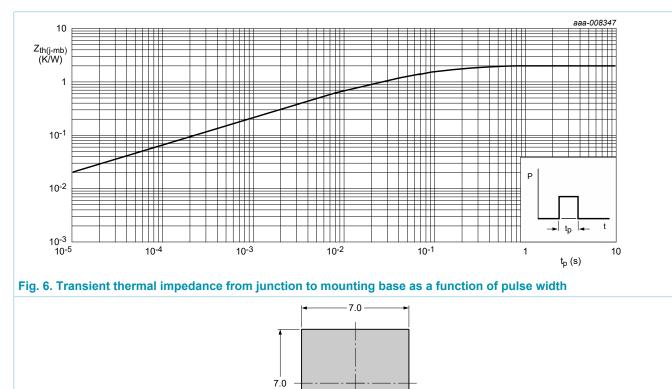


BT258S-800LT

SCR logic level, high temperature

8. Thermal characteristics

Table 5. The	rmal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	<u>Fig. 6</u>	-	-	2	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	Device mounted on a FR4 printed- circuit board, single-sided copper, tin- plated and standard footprint; Fig. 7	-	75	-	K/W



All dimensions are in mm Plastic meets requirements of UL94 V-O at 3.175 mm

2.15

2.5

Fig. 7. SOT428: minimum pad sizes for surface-mounting

BT258S-800LT

4.57

1.5

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SCR logic level, high temperature

9. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics		· ·			
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 8</u>	20	-	50	μA
IL	latching current	V_D = 12 V; I _G = 0.1 A; T _j = 25 °C; <u>Fig. 9</u>	-	0.4	10	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 10</u>	-	0.3	6	mA
V _T	on-state voltage	I _T = 16 A; T _j = 25 °C; <u>Fig. 11</u>	-	1.3	1.6	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 12	-	0.4	1	V
		V_D = 800 V; I _T = 0.1 A; T _j = 110 °C; Fig. 12	0.1	0.2	-	V
ID	off-state current	V _D = 800 V; T _j = 150 °C	-	0.5	2.5	mA
I _R	reverse current	V _R = 800 V; T _j = 150 °C	-	0.5	2.5	mA
Dynamic ch	aracteristics	· · · ·				
dV _D /dt	rate of rise of off-state voltage		35	70	-	V/µs
t _{gt}	gate-controlled turn-on time	I _{TM} = 10 A; V _D = 800 V; I _G = 5 mA; dI _G / dt = 0.2 A/μs; T _i = 25 °C	-	2	-	μs

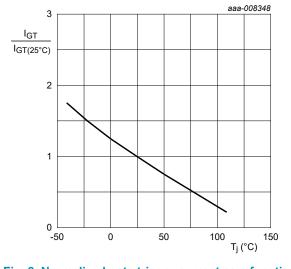
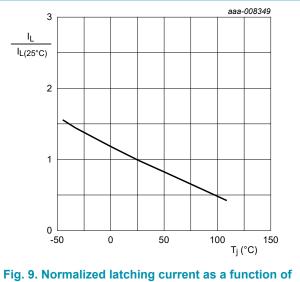


Fig. 8. Normalized gate trigger current as a function of junction temperature

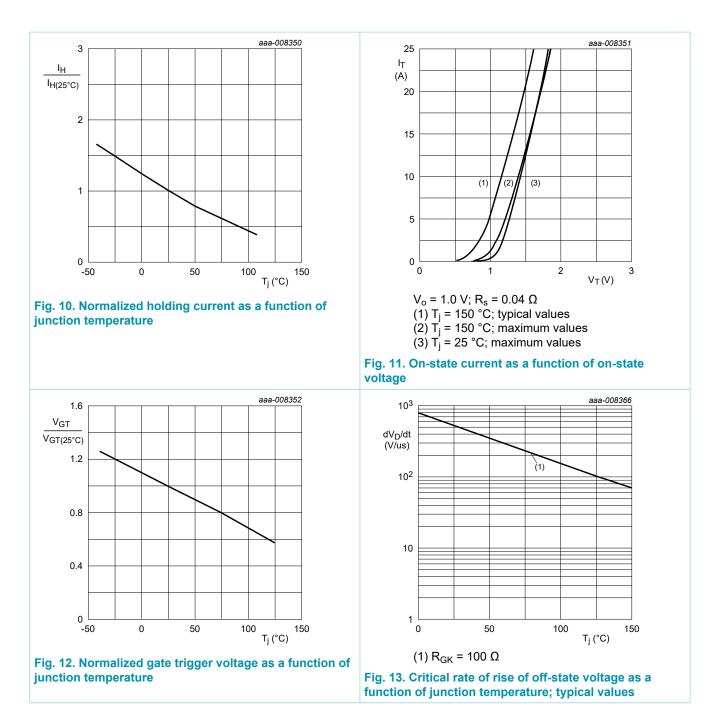


junction temperature

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8 / 12

SCR logic level, high temperature

10. Package outline

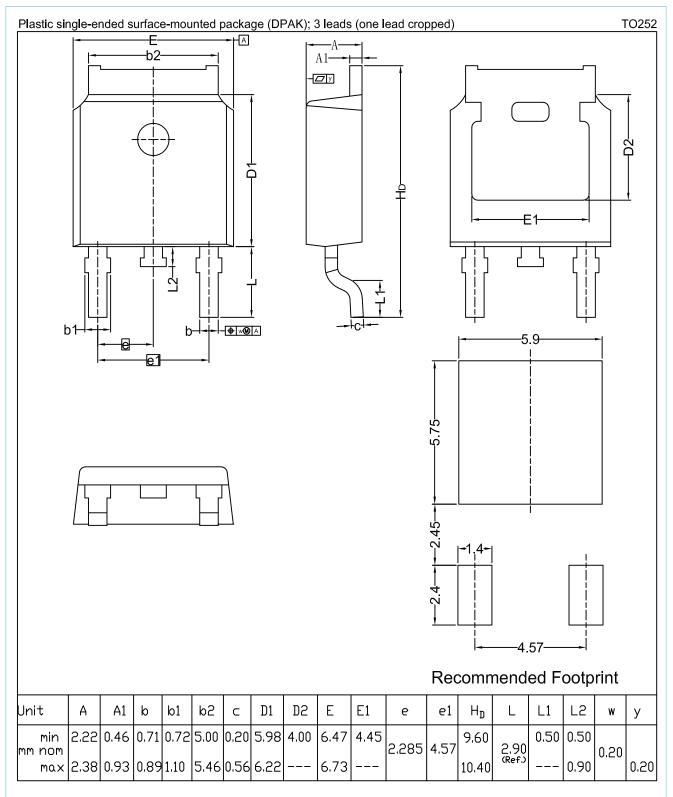


Fig. 14. Package outline DPAK (SOT428)

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11. Legal information

Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
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- [2] The term 'short data sheet' is explained in section "Definitions".
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BT258S-800LT

SCR logic level, high temperature

12. Contents

1.	General description	1
2.	Features and benefits	1
3.	Applications	1
4.	Quick reference data	1
5.	Pinning information	2
6.	Ordering information	2
7.	Limiting values	3
8.	Thermal characteristics	6
9.	Characteristics	7
10	. Package outline	9
11.	. Legal information	10

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BT258S-800LT